

#### **General Description**

This product family offers state of the art performance. It is designed for high frequency applications where high efficiency and high reliability are required.

#### **Features**

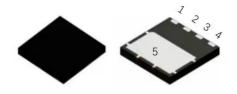
- Low conduction loss due to low VF
- Extremely low switching loss by tiny Qc
- Highly rugged due to better surge current
- Industrial standard quality and reliability

## **Applications**

- UPS
- Power Inverter
- High performance SMPS
- Power factor correction

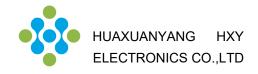
Ordering Part Number	Package	Marking
HC1D06065L	DFN8X8	HC1D06065L





DFN8X8 Package





Maximum Ratings (at Tc = 25 °C, unless otherwise specified)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	650	V
Surge Peak Reverse Voltage	$V_{RSM}$	650	V
DC Peak Reverse Voltage	$V_R$	650	V
Continuous Forward Current $T_{C} = 25^{\circ}C$ $T_{C} = 135^{\circ}C$ $T_{C} = 162^{\circ}C$	I <sub>F</sub>	23 12 6	А
Repetitive Peak Forward Surge Current $T_{C} = 25^{\circ}\text{C}, t_{p} = 10 \text{ms}, \text{Half Sine Pulse}$ $T_{C} = 110^{\circ}\text{C}, t_{p} = 10 \text{ms}, \text{Half Sine Pulse}$	I <sub>FRM</sub>	28 17	А
Non-Repetitive Forward Surge Current $T_C = 25^{\circ}\text{C}, t_p = 10 \text{ms}, \text{Half Sine Pulse}$ $T_C = 110^{\circ}\text{C}, t_p = 10 \text{ms}, \text{Half Sine Pulse}$	I <sub>FSM</sub>	48 43	А
$i^2$ dt value $T_C = 25^{\circ}C, t_p = 10$ ms, Half Sine Pulse $T_C = 110^{\circ}C, t_p = 10$ ms, Half Sine Pulse	∫i <sup>2</sup> dt	11.4 9.1	A <sup>2</sup> s
Power dissipation $T_{C} = 25^{\circ}C$ $T_{C} = 110^{\circ}C$	P <sub>tot</sub>	71 30	W
Operating junction Range	T <sub>j</sub>	-55 to +175	°C
Storage temperature Range	$T_{stg}$	-55 to +150	°C

## **Thermal Resistance**

Parameter	Symbol	Тур.	Unit
Thermal resistance, junction – case.	$R_{thJC}$	2.1	°C/W



## Electrical Characteristic (at Tc = 25 °C, unless otherwise specified)

Parameter	er Symbol Value			Unit	Test Condition		
Parameter	Syllibol	min.	typ.	max.	Unit	rest Condition	
						I <sub>F</sub> =6A	
Forward Voltage	V <sub>F</sub>	-	1.3	1.5	V	T <sub>j</sub> =25°C	
		-	1.5			T <sub>j</sub> =175°C	
						V <sub>R</sub> =650V	
Reverse Current	I <sub>R</sub>	-	-	50	μΑ	T <sub>j</sub> =25°C	
		-	-	200		T <sub>j</sub> =175°C	
Total Capacitive Charge	$Q_{C}$				nC	V <sub>R</sub> =400V,T <sub>j</sub> =25℃	
		1	18	1		$Q_C = \int_0^{V_R} C(V) dV$	
						T <sub>j</sub> =25℃, f=1MHz	
Total Capacitance	С	-	358	-	pF	V <sub>R</sub> =0V	
		-	36	-		V <sub>R</sub> =200V	
		-	30	-		V <sub>R</sub> =400V	

#### **Characteristics Curve**

Fig 1: Forward Characteristics

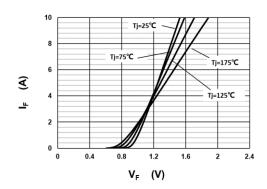


Fig 2: Reverse Characteristics

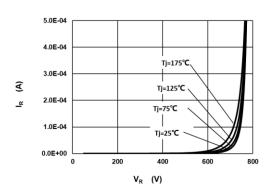


Fig 3: Current Derating

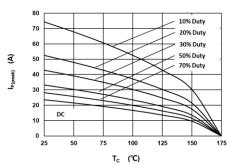


Fig 4: Power Derating

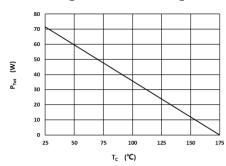


Fig 5: Capacitance vs. Reverse Voltage

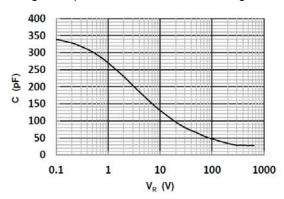


Fig 6: Reverse Charge vs. Reverse Voltage

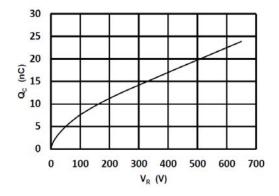
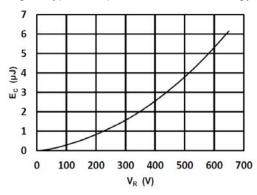


Fig 7: Typical Capacitance Stored Energy



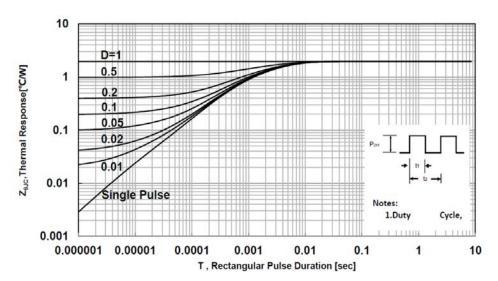
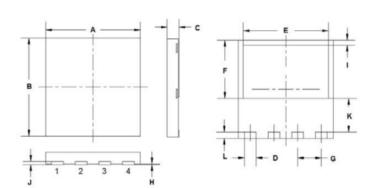


Fig 8: Transient Thermal Impandance

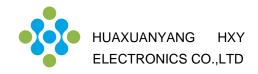
## **Package Dimensions**

Package DFN8X8



Unit: mm

Dimension	Min.	Max.
Α	7.90	8.10
В	7.90	8.10
С	0.75	0.95
D	0.90	1.10
E	7.10	7.30
F	4.65	4.85
G	1.80	2.20
Н	0.00	0.05
1	0.30	0.50
J	0.10	0.30
K	2.65	2.85
L	0.40	0.60



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